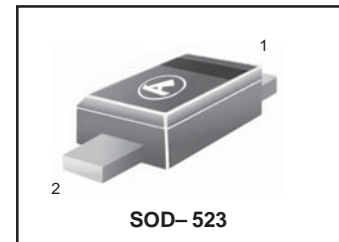


Variable Capacitance Diode for Tuner

FEATURES

- High capacitance ratio. (n =13.0 min)
- Ultra small Flat Package (UFP) is suitable for surface mount design.

HVC317B



DEVICE MARKING

HVC317B = A5

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V _R	35	V
Junction temperature	T _j	125	°C
Storage temperature	T _{stg}	- 55 to +125	°C

Notes 1. R_L = 10kΩ

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse current	I _{R1}	-	-	10	nA	V _R = 30V
	I _{R2}	-	-	100		V _R = 30V, T _A = 60°C
Capacitance	C ₁	9.00	-	11.5	pF	V _R = 1V, f = 1 MHz
	C ₂₅	0.60	-	0.80		V _R = 25V, f = 1 MHz
Capacitance ratio	n	13.0	-	-	-	C ₁ / C ₂₅
Series resistance	r _s	-	-	1.6	Ω	V _R = 5V, f = 470 MHz
Matching error	ΔC/C * 1	-	-	6.0	%	V _R = 1 to 25V, f = 1 MHz

Notes 1. C.C system (Continuous Connected taping system) enable to make any 10 pcs of ΔC/C continuous in a reel, expect extension to another group.

Calculate Matching Error,

$$\Delta C/C = \frac{(C_{\max} - C_{\min})}{C_{\min}} \times 100 (\%)$$

HVC317B

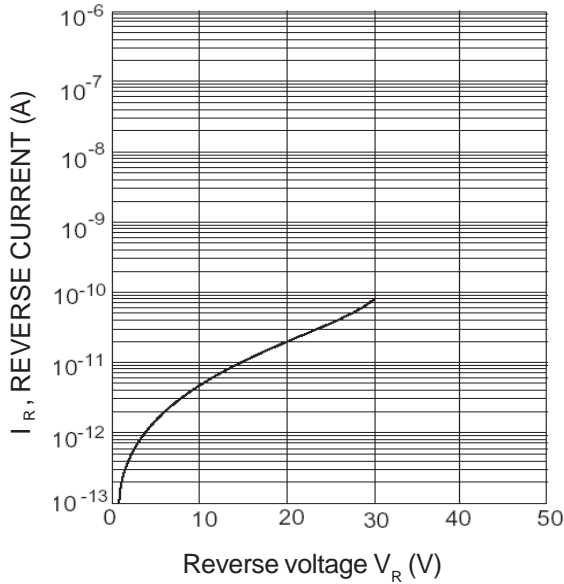


Fig.1 Reverse current Vs. Reverse voltage

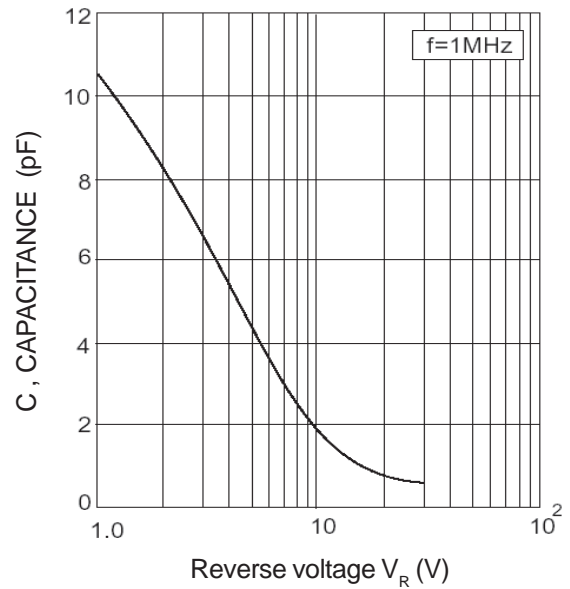


Fig.2 Capacitance Vs. Reverse voltage

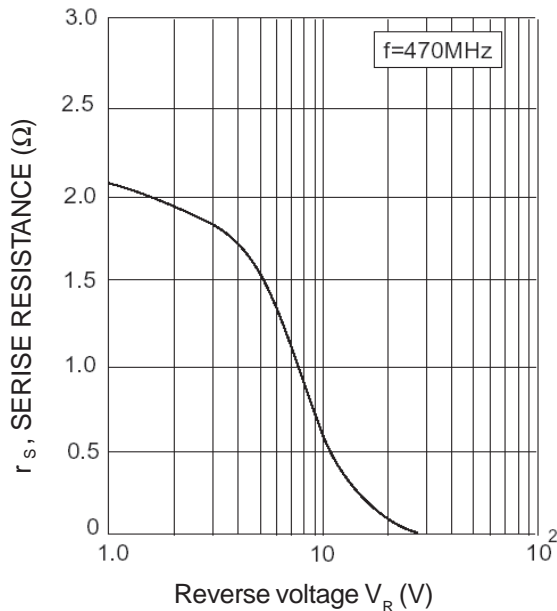


Fig.3 Series resistance Vs. Reverse voltage

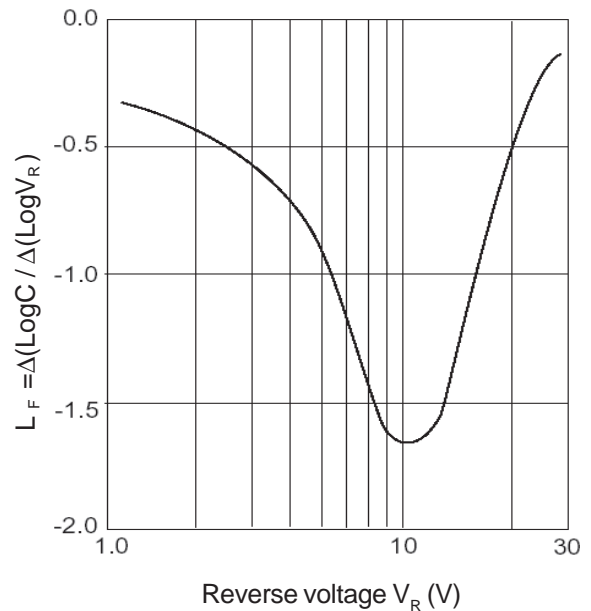


Fig.4 Linearity factor Vs. Reverse voltage